



EPS13D2 C 1 H E -20.000M

Spread Spectrum

Period Jitter

Start Up Time

Modulation Frequency

Storage Temperature Range

Frequency Stability
±100ppm Maximum over Operating Temperature of
-20°C to +70°C

Nominal Frequency 20.000MHz

Output Control Function

±1.50% Center Spread

Duty Cycle 50 ±10%

±1.50% Center Spread

10mSec Maximum -55°C to +125°C

ELECTRICAL SPECIFICATIONS Nominal Frequency ±100ppm Maximum over Operating Temperature of -20°C to +70°C (Inclusive of all conditions: Frequency **Frequency Stability** Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration.) ±5ppm First Year Maximum Aging at 25°C Supply Voltage 3.3Vdc ±0.3Vdc **Maximum Supply Voltage** -0.5Vdc to +7.0Vdc 30mA Maximum (Unloaded; Vdd=3.3Vdc) **Input Current Output Voltage Logic High (Voh)** Vdd-0.4Vdc Minimum (IOH=-8mA) **Output Voltage Logic Low (Vol)** 0.4Vdc Maximum (IOL=+8mA) Rise/Fall Time 2.7nSec Maximum (Measured at 20% to 80% of Waveform) **Duty Cycle** 50 ±10% (Measured at 50% of Waveform) **Load Drive Capability** 15pF Maximum **CMOS Output Logic Type Output Control Function** Tri-State (High Impedance Internal Pull Down Resistor of 100kOhms Typical on Pad 3, Internal Pull Up Resistor of 100kOhms Typical on Pad 1) Tri-State Input Voltage (Vih and Vil) 70% of Vdd Minimum or No Connection to Enable Output, 30% of Vdd Maximum to Disable Output **Tri-State Output Disable Time** 350nSec Maximum **Tri-State Output Enable Time** 350nSec Maximum **Disable Current** 20mA Maximum (Unloaded; Pad 1=Ground; Vdd=3.3Vdc)

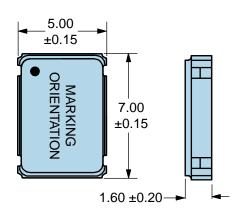
ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	
Gross Leak Test	MIL-STD-883, Method 1014, Condition C	
Mechanical Shock	MIL-STD-202, Method 213, Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010	
Vibration	MIL-STD-883, Method 2007, Condition A	

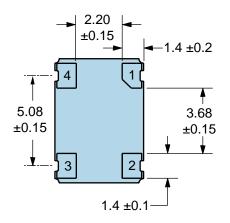
700pSec Maximum (Cycle to Cycle; Spread Spectrum-On; Vdd=3.3Vdc)

30kHz Minimum, 31.5kHz Typical, 33kHz Maximum



MECHANICAL DIMENSIONS (all dimensions in millimeters)



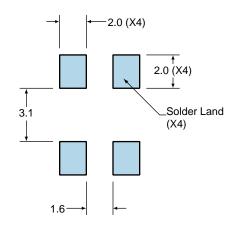


PIN	CONNECTION
1	Tri-State
2	Case/Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	ECLIPTEK
2	20.000M
3	SXXYZZ S=Configuration Designatol XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year

Suggested Solder Pad Layout

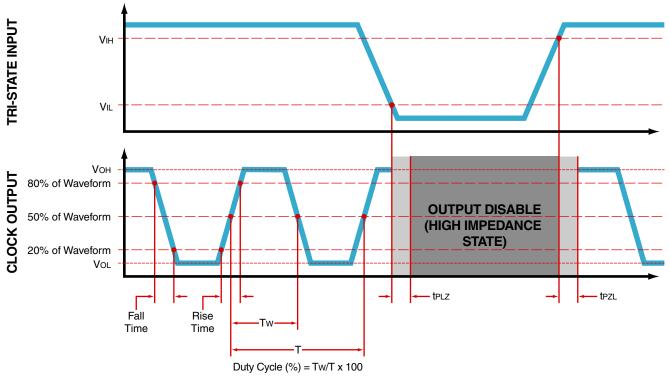
All Dimensions in Millimeters



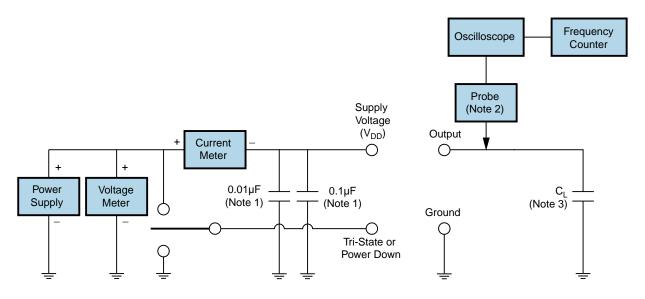
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



- Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _S TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.